BAS116TT1G

Switching Diode

Features

- Low Leakage Current Applications
- Medium Speed Switching Times
- Available in 8 mm Tape and Reel
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_A = 25°C)

Rating	Symbol	Max	Unit
Continuous Reverse Voltage	V_{R}	75	٧
Peak Forward Current	lF	200	mA
Peak Forward Surge Current	I _{FM(surge)}	500	mA

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation, FR-4 Board (Note 1) T _A = 25°C	P _D	225	mW
Derated above 25°C		1.8	mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{ heta JA}$	555	°C/W
Total Device Dissipation, FR-4 Board (Note 2) T _A = 25°C Derated above 25°C	P _D	360 2.9	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ hetaJA}$	345	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1

- 1. FR-4 @ Minimum Pad
- 2. FR-4 @ 1.0 × 1.0 Inch Pad



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CASE 463 SOT-416 STYLE 2



MARKING

AE = Specific Device Code
M = Date Code
Pb-Free Package

ORDERING INFORMATION

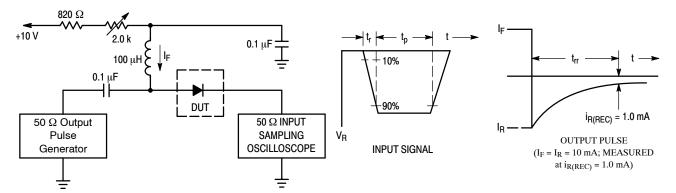
Device	Package	Shipping [†]		
BAS116TT1G	SOT-416 (Pb-Free)	3000 / Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

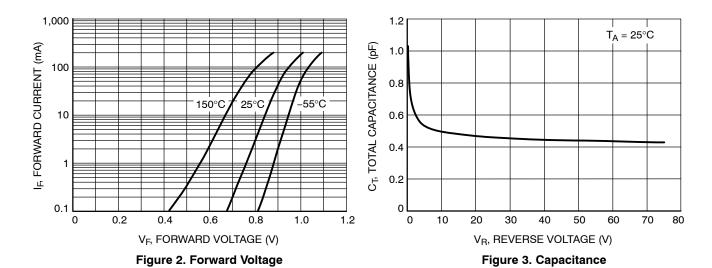
Characteristic	Symbol	Min	Max	Unit		
OFF CHARACTERISTICS						
Reverse Breakdown Voltage (I _{BR} = 100 μAdc)	V _(BR)	75	-	Vdc		
Reverse Voltage Leakage Current (V _R = 75 Vdc) (V _R = 75 Vdc, T _J = 150°C)	I _R	- -	5.0 80	nAdc		
Forward Voltage ($I_F = 1.0 \text{ mAdc}$) ($I_F = 10 \text{ mAdc}$) ($I_F = 50 \text{ mAdc}$) ($I_F = 150 \text{ mAdc}$)	V _F	- - - -	900 1000 1100 1250	mV		
Diode Capacitance (V _R = 0 V, f = 1.0 MHz)	C _D	-	2.0	pF		
Reverse Recovery Time (I _F = I _R = 10 mAdc) (Figure 1)	t _{rr}	_	3.0	μs		



- 1. A 2.0 $k\Omega$ variable resistor adjusted for a Forward Current (IF) of 10 mA.
- 2. Input pulse is adjusted so $I_{R(peak)}$ is equal to 10 mA.
- 3. $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

TYPICAL CHARACTERISTICS

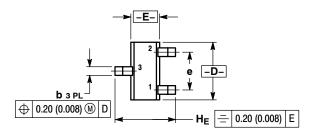


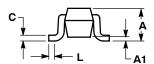
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PACKAGE DIMENSIONS

SC-75/SOT-416 CASE 463-01 **ISSUE F**



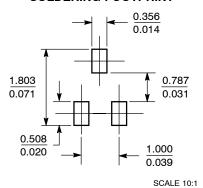


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI
- 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.70	0.80	0.90	0.027	0.031	0.035
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.15	0.20	0.30	0.006	0.008	0.012
С	0.10	0.15	0.25	0.004	0.006	0.010
D	1.55	1.60	1.65	0.059	0.063	0.067
Е	0.70	0.80	0.90	0.027	0.031	0.035
е	1.00 BSC			0.04 BSC		
L	0.10	0.15	0.20	0.004	0.006	0.008
HE	1.50	1.60	1.70	0.061	0.063	0.065

STYLE 2: PIN 1. ANODE 2. N/C 3. CATHODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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